



serious problem concerned to e

5 maintaining required transmission characteristics.

In such devices, a serious problem resides in how

10 (great problem) how to connect the external electric circuit

The high-frequency package has heretofore been

20 waveguide is once connected to a microstrip line in the

Recently, furthermore, there has also been proposed a

25 method by which the high-frequency package is directly

According to this proposal, quartz is buried in a portion

30 of a closure member forming a cavity in which the device

the waveguide to a waveguide-microstrip line converter

35 substrate installed in the cavity.





5

10

15

20

35









5

10

20

25

30







dielectric substrate 1, the grounded layer 7 is formed on the back surface of the dielectric substrate 1, and the slot 6 is formed in the grounded layer 7 so as to be opposed to an end of the signal transmission line 5.

5 Their structures are as described concerning the high-frequency package A1 shown in Fig. 1a.

In the high-frequency package A2 of Fig. 2a, the first dielectric layer 14 and the second dielectric layer 15 are laminated on the whole surface of the grounded layer 7 formed on the bottom surface of the dielectric substrate 1. The above-mentioned patched conductor 10 is provided in the interface between the first dielectric layer 14 and the second dielectric layer 5 so as to be opposed to the slot 6 in the grounded layer 7. As will be obvious from the bottom view of Fig. 2b, further, plural vertical conductors 16 are arranged penetrating through the first dielectric layer 14 and the second dielectric layer 15 so as to surround the patched conductor 10 and the slot 6 with the patched conductor 10 as a center. The vertical conductors 16 are electrically connected to the grounded layer 7, the region surrounded by the vertical conductors 16 serves as the waveguide connection portion C2, the region of the first dielectric layer 14 surrounded by the vertical conductors 16 corresponds to the first dielectric portion, and the region of the second

dielectric layer 15 surrounded by the vertical conductors 16 corresponds to the second dielectric portion. *as shown in Fig 2A*

It is desired that the gap among the vertical  
conductors 16 is set to be one-fourth the wavelength  $\lambda$  of  
the signals to prevent the leakage of electromagnetic  
waves from the waveguide connection portion C2 to the  
external side. In order to more reliably prevent the  
leakage of the electromagnetic waves, further, it is  
desired to provide a conductor layer 17 in the interface  
between the first dielectric layer 14 and the second

dielectric layer 15 outside the vertical conductors 16, <sup>as shown in Fig 2a</sup>

On the surface of the second dielectric layer 15 is further formed an electrically conducting layer 18 that is electrically connected to the vertical conductors 16. As shown in Fig. 2c, the flange B' of the waveguide B1 is mounted on the electrically conducting layer 18 by junction means using an electrically conducting adhesive such as a brazing material or by mechanical junction means such as fastening using a screw. The waveguide B1 and the grounded layer 7 share the same potential.

The high-frequency package A2 of the structure shown in Fig. 2a is more advantageous than the high-frequency package A1 shown in Fig. 1a in regard to that the waveguide B1 is connected to the waveguide connection portion C2 by mechanical means such as using a screw without at all giving damage to the dielectric substrate 1. The whole thickness and the strength of the package A2 are larger than that of the package A1. Therefore, the package A2 enables the waveguide to be connected more reliably than the package A1. The high-frequency package A2 is further superior to the high-frequency package A1 even from the standpoint of productivity. That is, the high-frequency package A2 can be produced by firing the dielectric substrate 1, first dielectric layer 14, second dielectric layer 15, semiconductor layers 17, 18 and vertical conductors 16 at one time relying upon the known ceramic lamination technology. When the high-frequency package A1 is produced by being fired at one time, however, it is likely that the unfired ceramic block which constitutes the waveguide connection portion peels in a stage of before being fired. In the case of the high-frequency package A2, however, the waveguide connection portion is formed of the first dielectric layer 14 and the second dielectric layer and, hence, the unfired ceramic sheet forming these dielectric layers does not peel.

According to the above-mentioned high-frequency package A2 of the present invention, the waveguide B1 can also be connected via a connection member 13 having an opening surface 13a as shown in Fig. 2d. That is, the connection member 13 is mounted on the conductor layer 18 on the surface of the second dielectric layer 15 by using an electrically conducting adhesive such as a brazing material, and the flange B' of the waveguide B1 is connected to the connection member 13 using an electrically conducting adhesive agent or a screw, in order to firmly join the high-frequency package A2 and the waveguide B1 together and to enhance the reliability of connection between the two. In this case, the connection member 13 may be formed of a conductor such as a metal or an insulator such as ceramics or an organic resin. When the connection member 13 made of an insulator is used, it is desired to form a conductor layer on the opening surface 13a of the connection member 13 to maintain electric connection between the waveguide B1 and the grounded layer 7.

The structure of the wiring board of the present invention was described above by way of a package mounting a semiconductor device which was air-tightly sealed with a closure with reference to Figs. 1a and 2a. The invention can similarly be applied even to a circuit substrate for mounting a package holding semiconductor devices and to a circuit substrate for directly mounting semiconductor devices. In the present invention, further, the connection characteristics to the waveguide vary depending upon the shapes of the slot 6 formed in the grounded layer 7 and of the patched conductor 10. It is therefore desired to determine a predetermined relationship for them.

Fig. 3 is a plan view illustrating a positional relationship among the slot 6, patched conductor 10 and

signal transmission line 5 in the high-frequency packages of Figs. 1a and 2a. Referring to Fig. 3, it is desired that the length SL (maximum length in a direction at right angles with the signal transmission line 5) of the slot 6 formed in the grounded layer 7 is set to be 1 to 2 times and, particularly, 10/8 to 14/8 times as great as the wave length  $\lambda$  of signals propagating through the dielectric substrate 1. That is, upon setting the length SL of the slot 6 to lie within the above-mentioned range, the patched conductor 10 does not work as an antenna or a dipole for exciting the signals but works to adjust the electromagnetic field distribution by dividing the signals excited through the slot 6, so that the electromagnetic field distribution becomes continuous from the slot 6 to the waveguide B1. Compared to when the patched conductor 10 is used for exciting the signals, therefore, the band for propagating the signals is widened and dispersion in the frequency of the transmitted signals decreases. When the maximum length SL of the slot 6 is smaller than the wave length  $\lambda$  of the signals, the patched conductor 10 can be used for exciting the signals (can be used as a dipole antenna) arousing, however, such a problem that the band for transmitting the signals becomes narrow.

As described above, the patched conductor 10 does not work for exciting the signals but works for adjusting the distribution by dividing the electromagnetic waves, making it possible to eliminate dependence of the frequency of transmission signals upon the length of the patched conductor 10 and, hence, to realize a wide band and decreased dispersion.

According to the present invention, the patched conductor 10 has nearly a rectangular shape as shown in Fig. 3. Here, when a maximum length of the patched conductor 10 is denoted by W1 in a direction at right angles with the direction of the signal transmission line



5 and a maximum length thereof by  $L_1$  in a direction in parallel with the signal transmission line 5, it is desired that  $L_1 \geq W_1$ . It is further desired that the length  $L_1$  of the patched conductor satisfies the conditions represented by the following formula with respect to the wave length  $\lambda$  of the signals,

$$10\lambda/64 \leq L_1 \leq 31\lambda/64$$

or

$$33\lambda/64 \leq L_1 \leq 63\lambda/64.$$

10 When the above conditions are satisfied, radiation of undesired electromagnetic waves from the patched conductor 10 is suppressed, and continuous electromagnetic field distribution is effectively maintained.

In the above-mentioned embodiment, there is no particular limitation on the thickness of the first dielectric portion (thickness of the first dielectric block 9 or thickness of the first dielectric layer 14) or on the thickness of the second dielectric portion (thickness of the second dielectric block 10 or thickness of the second dielectric layer 15). In order to bring the electromagnetic waves emitted from the slot 6 into match with the electromagnetic field distribution in the waveguide, however, it is desired that the total thickness of the first dielectric portion and of the second dielectric portion is not smaller than  $1/8$  the wave length  $\lambda$  of the signals and, further, that the thickness of the first dielectric portion is not smaller than  $1/16$  the wave length  $\lambda$  and the thickness of the second dielectric portion is not smaller than  $1/16$  the wave length  $\lambda$ . When the second dielectric portion is not formed (the patched conductor 10 is exposed) or the thickness of the second dielectric portion is extremely thinner than that of the first dielectric portion, the patched conductor 10 is one-sided in the connection portion whereby the electromagnetic field is not continuous smoothly from the



minimum distance (shortest distance)  $L_2$  to the signal transmission line 5 of not larger than  $2\lambda$ , and have a maximum length  $L_3$  which is from  $\lambda/8$  to  $7\lambda/8$  and, particularly, from  $\lambda/4$  to  $3\lambda/4$  in the direction in' parallel with the signal transmission line 5. As far as these conditions are satisfied by the resonance conductor portions 20, undesired radiation of electromagnetic waves from the resonance conductor portions 20 is effectively suppressed, resonance with the signal transmission line 5 increases, and loss of signal transmission decreases most effectively.

Figs. 4b to 4e illustrate other arrangements of the resonance conductor portions 20. The resonance conductor portions 20 may be intermittently formed maintaining a gap of one-eighth the wave length  $\lambda$  of the signals as shown in, for example, in a plan view of Fig. 4b, or the resonance conductor portions 20 may be electrically connected to the grounded layer 7 through vertical conductors 11 as shown in a side sectional view of Fig. 4c. In the examples of Figs. 4a to 4c, further, the resonance conductor portions 20 are formed in flush with the signal transmission line 5. However, the resonance conductor portions 20 may be formed inside the dielectric substrate 1 as shown in a side sectional view of Fig. 4d as far as they are located on the upper side of the grounded layer 7. In this case, too, it is desired that the shortest distance  $L_2$  from the resonance conductor portions 20 to the signal transmission line 5 is not larger than two times the wave length  $\lambda$  of the signals.

As described above, further, it is most desired that the plural resonance conductor portions 20 are arranged to be symmetrical with respect to the signal transmission line 5. As far as there takes place resonance, however, they need not necessarily to be symmetrically arranged or need not be arranged in parallel with the signal



In the high-frequency package A3 of Fig. 5, the signals from the signal transmission line 5 pass, due to electromagnetic coupling, through the slot 6 and dielectric region C3, propagate from the surface of the dielectric region C3 and are continuously connected to the waveguide passing through the cavity 26 in the third dielectric layer 25. The conversion loss from the signal transmission line 5 through up to the waveguide is not decreased to a sufficient degree if the center of the waveguide that is connected is deviated from the center of the slot 6. In this case, the transmission characteristics may often be dispersed. By providing the third dielectric layer 25 as shown in Fig. 5, however, the deviation in position can be effectively reduced between the center of the waveguide and the center of the slot 6, making it possible to greatly decrease the conversion loss and to prevent dispersion in the transmission characteristics. In the embodiment of Fig. 5, therefore, there is no particular limitation on the thickness of the third dielectric layer 25. From the standpoint of greatly decreasing the conversion loss, however, it is desired that the thickness of the third dielectric layer 25 is not smaller than 2.5%, preferably, not smaller than 3% and, most preferably, not smaller than 4% of the wave length  $\lambda$  of the signals.

In the high-frequency package A3 of Fig. 5, further, the thickness of the package as a whole becomes large due to the formation of the third dielectric layer 25 giving an advantage of an increased strength of the package. Further, the third dielectric layer 25 need not be of a single layer but may consist of plural layers, and multi-layer circuits may be formed in the first to third dielectric layers, as a matter of course.

In the high-frequency package A2 shown in Figs. 2a and 2b, the outer shape of the region surrounded by the

vertical conductors 16, i.e., the outer shape of the waveguide connection portion C2, has the same size as the opening in cross section of the waveguide B1 that is connected to the package A2. As shown in a side sectional view of Fig. 6a, however, the outer shape of the waveguide connection portion C2 may be selected to be smaller than the cross section of opening of the waveguide B1. As described above, when the center of the waveguide is deviated from the center of the slot 6, the conversion loss from the signal transmission line 5 through up to the waveguide is not decreased to a sufficient degree, and the transmission characteristics will be dispersed, too. By decreasing the outer shape of the waveguide connection portion C2 as shown in Fig. 6a, the deviation in position can be effectively decreased between the center of the waveguide B1 and the center of the slot 6, whereby the conversion loss greatly decreases and dispersion in the transmission characteristics is effectively prevented.

In Fig. 6a, when the opening of the waveguide B1 has a rectangular shape in cross section, it is desired that the waveguide connection portion C2 has a rectangular outer shape smaller than the opening in cross section of the waveguide B1 as shown in a sectional plan view of Fig. 6b. In Fig. 6b, for example, when the sides of the opening of the waveguide B1 of a rectangular shape in cross section are denoted by  $P^1$  (long side) mm and  $P^2$  (short side) mm, and the sides of the rectangular waveguide connection portion C2 at a position corresponding to the sides  $P^1$ ,  $P^2$ , are denoted by  $Q^1$  (long side) mm and  $Q^2$  (short side) mm, then, there hold relations  $P^1 > Q^1$  and  $P^2 > Q^2$ , as a matter of course. From the standpoint of greatly decreasing the conversion loss and preventing dispersion in the transmission characteristics, however, it is desired that following conditions are satisfied concerning the long sides,

and the following conditions are satisfied concerning the short sides,

5 In the example of Fig. 6a like in Fig. 2c, the flange B' of the waveguide B1 is directly joined to the conductor layer 18 on the second dielectric layer 15. As shown in Fig. 2c, however, the flange B' of the waveguide B1 may be joined via the connection member 13 or the third

15 In the present invention described above, the dielectric members used for forming the dielectric substrate 1, various dielectric layers and dielectric blocks, may be known ceramics, organic resins or composite materials thereof. As the ceramics, for example, there  
20 can be used ceramic materials such as  $\text{Al}_2\text{O}_3$ ,  $\text{AlN}$  or  $\text{Si}_3\text{N}_4$ , or a glass material, or a glass ceramic material which is a composite material of the glass and an inorganic filler such as  $\text{Al}_2\text{O}_3$ ,  $\text{SiO}_2$  or  $\text{MgO}$ . By using these staring  
25 and a layer having a predetermined shape are molded and are fired to obtain a dielectric substrate, various dielectric layers and dielectric blocks.

Further, the transmission lines for transmitting signals and the grounded layers can be formed by using a high-melting metal such as tungsten or molybdenum or by using a low-resistance metal such as gold, silver or copper. These materials may be suitably selected depending upon the dielectric material that is used and can be integrally formed relying upon the existing lamination technology.

## EXPERIMENTS

(Experiment 1)

Thickness of the dielectric substrate 1: 0.15 mm

Thickness of the second dielectric block 11: 0.2 mm

It will be understood from Fig. 7 that the package and the waveguide have been connected together maintaining such favorable transmission characteristics as S21 (loss) of zero dB and S11 (reflection) of -25 dB at 77 GHz.

further  
clap  
new!



5

10

15

20

25

30

Table 1

| Sample No. | Length of slot |                                    | Conductor      |                                    | S21 (dB) |      |       | Band |
|------------|----------------|------------------------------------|----------------|------------------------------------|----------|------|-------|------|
|            | Length SL (mm) | Ratio to the wave length $\lambda$ | Length L1 (mm) | Ratio to the wave length $\lambda$ | Average  | Best | Worst |      |
| *1         | 0.93           | 7/8                                | 0.53           | 1/2                                | 1.81     | 1.55 | 1.93  | 8    |
| *2         | 2.26           | 17/8                               | 0.53           | 1/2                                | 1.8      | 1.53 | 1.97  | 8    |
| 3          | 1.06           | 1                                  | 0.53           | 1/2                                | 1.72     | 1.54 | 1.84  | 10   |
| 4          | 1.33           | 10/8                               | 0.53           | 1/2                                | 1.67     | 1.48 | 1.78  | 10   |
| 5          | 1.86           | 14/8                               | 0.53           | 1/2                                | 1.66     | 1.49 | 1.78  | 10   |
| 6          | 2.13           | 2                                  | 0.53           | 1/2                                | 1.73     | 1.53 | 1.83  | 10   |
| 7          | 1.2            | 10/8                               | 0.53           | 1/2                                | 1.57     | 1.42 | 1.71  | 11   |
| 8          | 1.2            | 10/8                               | 0.53           | 1/2                                | 1.56     | 1.41 | 1.7   | 11   |
| 9          | 1.2            | 10/8                               | 0.15           | 9/64                               | 1.55     | 1.4  | 1.69  | 11   |
| 10         | 1.2            | 10/8                               | 0.17           | 10/64                              | 1.49     | 1.36 | 1.62  | 13   |
| 11         | 1.2            | 10/8                               | 0.515          | 31/64                              | 1.52     | 1.39 | 1.65  | 13   |
| 12         | 1.2            | 10/8                               | 0.55           | 33/64                              | 1.52     | 1.38 | 1.64  | 13   |
| 13         | 1.2            | 10/8                               | 0.55           | 63/64                              | 1.5      | 1.36 | 1.62  | 13   |
| 14         | 1.2            | 10/8                               | 1.06           | 1                                  | 1.56     | 1.41 | 1.69  | 12   |
| *15        | 0.66           | 5/8                                | —              | —                                  | 1.9      | 2.3  | 1.5   | 0    |

Sample marked with \* are those of Reference Examples.

From Table 1, in the case of the sample No. 1 having the length SL of slot of  $7/8\lambda$ , the loss S21 (average) was 1.81 dB and in the case of the sample No. 2 having SL of  $17/8\lambda$ , the loss S21 (average) was 1.8 dB.

5 In the case of the samples Nos. 3 to 14 having SL of not smaller than  $1\lambda$  but not larger than  $2\lambda$ , the losses S21 (average) were smaller than 1.8 dB, the bands were not smaller than 10 GHz and the dispersion was not larger than 0.3 dB, thus exhibiting favorable results.

10 Among them, the samples Nos. 7 to 9 and 10 to 14 in which L1 and W1 of the patched conductor 10 were  $L1 \geq W1$ , and the samples Nos. 10 to 13 in which L1 was  $10\lambda/64$  to  $31\lambda/64$  or  $33\lambda/64$  to  $63\lambda/64$ , exhibited the losses S21 (average) of not larger than 1.6 dB and bands of not  
15 smaller than 11 GHz, offering further superior properties. (Experiment 3)

The high-frequency package of Fig. 2a forming the resonance conductor portion of the structure shown in Figs. 4a to 4e was prepared in the same manner as in  
20 Experiment 2, and the transmission characteristics of the connection to the waveguide were evaluated based upon the finite element method. The results were as shown in Table 2.

In Table 2, S21 represents transmission losses of  
25 signals from the signal transmission line 5 to the waveguide when the frequency is 68 GHz.

In all packages, the real dielectric constant  $\epsilon_1$  of the surface of the dielectric substrate 1 to the line 5 was presumed to be 6.0 and the wave length  $\lambda$  of signals  
30 was presumed to be 1.8 mm from the following formula,

$$\lambda_0/(\epsilon_1)^{1/2} = 0.408 \times \lambda_0$$

When the resonance conductor portions were formed inside the dielectric substrate 1 (Fig. 4d), the wave length  $\lambda$  of signals was presumed to be 1.47 mm from the  
35 following formula,

[illegible]

35

Table 2

| Sample No. | Structure of resonance conductor | Resonance conductor         |                            |                   | Loss<br> S21 <br>(dB) |                            |
|------------|----------------------------------|-----------------------------|----------------------------|-------------------|-----------------------|----------------------------|
|            |                                  | Distance<br>L2 (mm)         | Relation to<br>wave length | Length<br>L3 (mm) |                       | Relation to<br>wave length |
| *1         | Fig.4a                           | without resonance conductor |                            |                   | 1.6                   |                            |
| 2          | Fig.4a                           | 4.5                         | 2.5λ                       | 1.8               | 1.0λ                  | 1.1                        |
| 3          | Fig.4a                           | 3.6                         | 2.0λ                       | 1.8               | 1.0λ                  | 0.88                       |
| 4          | Fig.4a                           | 1.8                         | 1.0λ                       | 1.8               | 1.0λ                  | 0.83                       |
| 5          | Fig.4a                           | 1.8                         | 1.0λ                       | 1.58              | 0.875λ                | 0.78                       |
| 6          | Fig.4a                           | 1.8                         | 1.0λ                       | 1.35              | 0.75λ                 | 0.74                       |
| 7          | Fig.4a                           | 1.8                         | 1.0λ                       | 0.45              | 0.25λ                 | 0.75                       |
| 8          | Fig.4a                           | 1.8                         | 1.0λ                       | 0.23              | 0.125λ                | 0.81                       |
| 9          | Fig.4b                           | 1.8                         | 1.0λ                       | 1.35              | 0.75λ                 | 0.75                       |
| 10         | Fig.4c                           | 1.8                         | 1.0λ                       | 1.35              | 0.75λ                 | 0.75                       |
| 11         | Fig.4d                           | 1.47                        | 1.0λ                       | 1.35              | 0.75λ                 | 0.74                       |
| 12         | Fig.4e                           | 1.8                         | 1.0λ                       | 1.35              | 0.75λ                 | 0.76                       |

Samples marked with \* are those of Reference Examples

When the distance L2 between the resonance conductor portion and the signal transmission line 5 was not larger than  $2\lambda$  (samples Nos. 3 to 12), the losses were not larger than 0.88 dB. When the length L3 of the resonance conductor portion was  $\lambda/8$  to  $7\lambda/8$  (samples Nos. 5 to 12), the losses were not larger than 0.81 dB.

(Experiment 4)

The wave length  $\lambda$  of signals in the dielectric substrate was calculated presuming that the wave length of signals at 94 GHz in the air of a dielectric constant of 1.0 was 3.19 mm.

Table 3

| Sample No. | Thickness of 3rd dielectric layer | Ratio to signal wave length $\lambda$ (%) | S21 (dB) |      |       | Remarks |
|------------|-----------------------------------|---|----------|------|-------|---------|
|            |                                   |   | Average  | Best | Worst |         |
| 1          | none                              | —   | 3.71     | 3.37 | 4.05  | 0.68    |
| 2          | 0.064                             | 2   | 3.65     | 3.35 | 3.94  | 0.59    |
| 3          | 0.080                             | 2.5                                       | 3.60     | 3.36 | 3.84  | 0.48    |
| 4          | 0.096                             | 3   | 3.56     | 3.34 | 3.78  | 0.44    |
| 5          | 0.128                             | 4   | 3.55     | 3.35 | 3.74  | 0.39    |
| 6          | 0.160                             | 5   | 3.55     | 3.35 | 3.73  | 0.38    |
| 7          | 0.160                             | 5   | 3.54     | 3.34 | 3.72  | 0.38    |

conductor  
inside  
dielectric  
region

15 (Experiment 5)

25        The waveguide was joined to the sample substrate by fastening the flange using a screw via a connection portion of a connection member 13 (Fe-Co-Ni alloy) as shown in Fig. 2d.

After having evaluated the characteristics of the sample substrates, the thermal shock testing was conducted to evaluate the reliability. The conditions consisted of a temperature cycle testing in a liquid vessel, and the samples were held at 0 °C and at 100 °C for 5 minutes, respectively. The number of samples was 10. When any one of the sample substrates was broken, the number of cycles



5

15

20

25

30

35

Table 4

| Sample No. | Size of waveguide connection portion |   |                     |  | S21 (dB) |                       | Number of cycles until reliability breaks |
|------------|--------------------------------------|---|---------------------|--|----------|-----------------------|---|
|            | Q <sup>2</sup> (mm)                  | Ratio to short side P <sup>2</sup> of waveguide | Q <sup>1</sup> (mm) | Ratio to long side P <sup>1</sup> of waveguide | Average  | Best Worst Dispersion |   |
| *1         | 1.27                                 | 1   | 2.54                | 1  | 3.67     | 3.32 3.98             | 100                                       |
| 2          | 1.22                                 | 0.96  | 2.49                | 0.98   | 3.58     | 3.31 3.86             | 300                                       |
| 3          | 1.17                                 | 0.92  | 2.44                | 0.96   | 3.56     | 3.31 3.8              | >1000                                     |
| 4          | 1                                    | 0.79  | 2                   | 0.79   | 3.52     | 3.29 3.75             | >1000                                     |
| 6          | 0.762                                | 0.6   | 1.524               | 0.6  | 3.56     | 3.32 3.8              | >1000                                     |
| 7          | 0.66                                 | 0.52  | 1.42                | 0.56   | 3.67     | 3.43 3.81             | >1000                                     |

Samples marked with \* are those of Reference Examples.

Table 4 (tells) that in the case of the sample No. 1 in which the size of the dielectric region was set to be same as the opening in cross section of the waveguide, dispersion in the loss S21 was great among the substrates, and cracks have occurred in the junction interface between the ceramics and the connection member after 100 cycles.

When the size of the dielectric region was selected to be smaller than the opening in cross section of the waveguide as in the samples Nos. 2 to 6, the dispersion could be decreased, and the substrates did not break until after 300 cycles in the reliability testing.

In the samples Nos. 3, 4, 5 and 6 in which the dielectric region was further decreased, the dispersion could be further decreased, and the reliability could be maintained up to 1000 cycles in the thermal shock testing.

20

25

30

35

000000-1100